

SN75LVDS179, SN75LVDS180, SN75LVDS050, SN75LVDS051 HIGH-SPEED DIFFERENTIAL LINE DRIVERS AND RECEIVERS

SLLS361A – JUNE 1999 – REVISED MARCH 2000

- Meets or Exceeds the Requirements of ANSI TIA/EIA-644-1995 Standard
- Signaling Rates up to 155 Mbps
- Operates From a Single 3.3-V Supply
- Low-Voltage Differential Signaling With Typical Output Voltages of 350 mV and a 100 Ω Load
- LVTTTL Input Levels are 5 V Tolerant
- Driver is High Impedance When Disabled or With $V_{CC} < 1.5$ V
- Receiver has Open-Circuit Fail Safe
- Surface-Mount Packaging – D Package (SOIC)
- Characterized For Operation From 0°C to 70°C

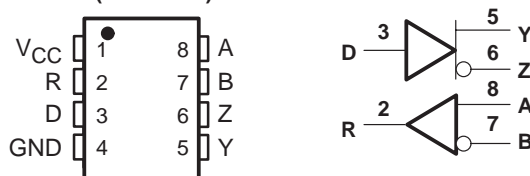
description

The SN75LVDS179, SN75LVDS180, SN75LVDS050, and SN75LVDS051 are differential line drivers and receivers that use low-voltage differential signaling (LVDS) to achieve signaling rates as high as 155 Mbps. The TIA/EIA-644 standard compliant electrical interface provides a minimum differential output voltage magnitude of 247 mV into a 100 Ω load and receipt of 100 mV signals with up to 1 V of ground potential difference between a transmitter and receiver.

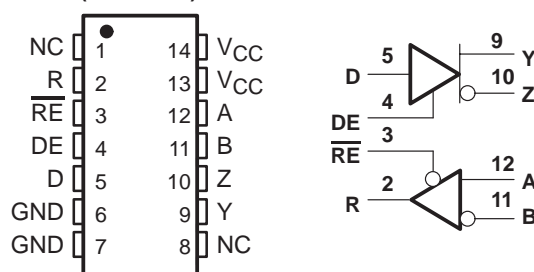
The intended application of this device and signaling technique is for point-to-point baseband data transmission over controlled impedance media of approximately 100 Ω characteristic impedance. The transmission media may be printed-circuit board traces, backplanes, or cables. (Note: The ultimate rate and distance of data transfer is dependent upon the attenuation characteristics of the media, the noise coupling to the environment, and other application specific characteristics).

The SN75LVDS179, SN75LVDS180, SN75LVDS050, and SN75LVDS051 are characterized for operation from 0°C to 70°C.

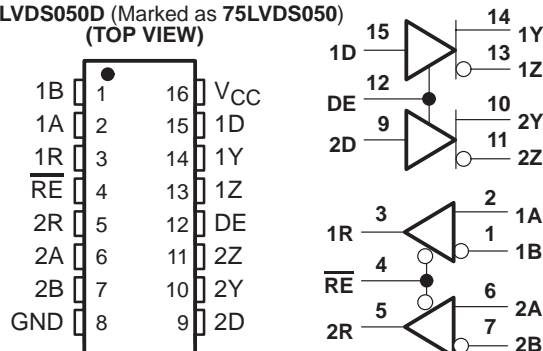
SN75LVDS179D (Marked as DS179 or 7LS179)
(TOP VIEW)



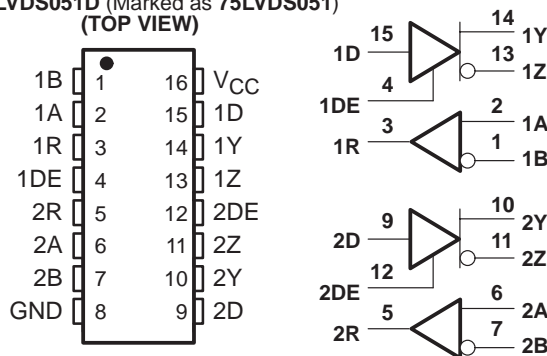
SN75LVDS180D (Marked as 7LVDS180)
(TOP VIEW)



SN75LVDS050D (Marked as 75LVDS050)
(TOP VIEW)



SN75LVDS051D (Marked as 75LVDS051)
(TOP VIEW)



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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SN75LVDS179, SN75LVDS180, SN75LVDS050, SN75LVDS051 HIGH-SPEED DIFFERENTIAL LINE DRIVERS AND RECEIVERS

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Function Tables

SN75LVDS179 RECEIVER

INPUTS	OUTPUT
$V_{ID} = V_A - V_B$	R
$V_{ID} \geq 100 \text{ mV}$	H
$-100 \text{ mV} < V_{ID} < 100 \text{ mV}$?
$V_{ID} \leq -100 \text{ mV}$	L
Open	H

H = high level, L = low level, ? = indeterminate

SN75LVDS179 DRIVER

INPUT	OUTPUTS	
D	Y	Z
L	L	H
H	H	L
Open	L	H

H = high level, L = low level

SN75LVDS180, SN75LVDS050, and SN75LVDS051 RECEIVER

INPUTS		OUTPUT
$V_{ID} = V_A - V_B$	$\overline{\text{RE}}$	R
$V_{ID} \geq 100 \text{ mV}$	L	H
$-100 \text{ mV} < V_{ID} < 100 \text{ mV}$	L	?
$V_{ID} \leq -100 \text{ mV}$	L	L
Open	L	H
X	H	Z

H = high level, L = low level, Z = high impedance,
X = don't care

SN75LVDS180, SN75LVDS050, and SN75LVDS051 DRIVER

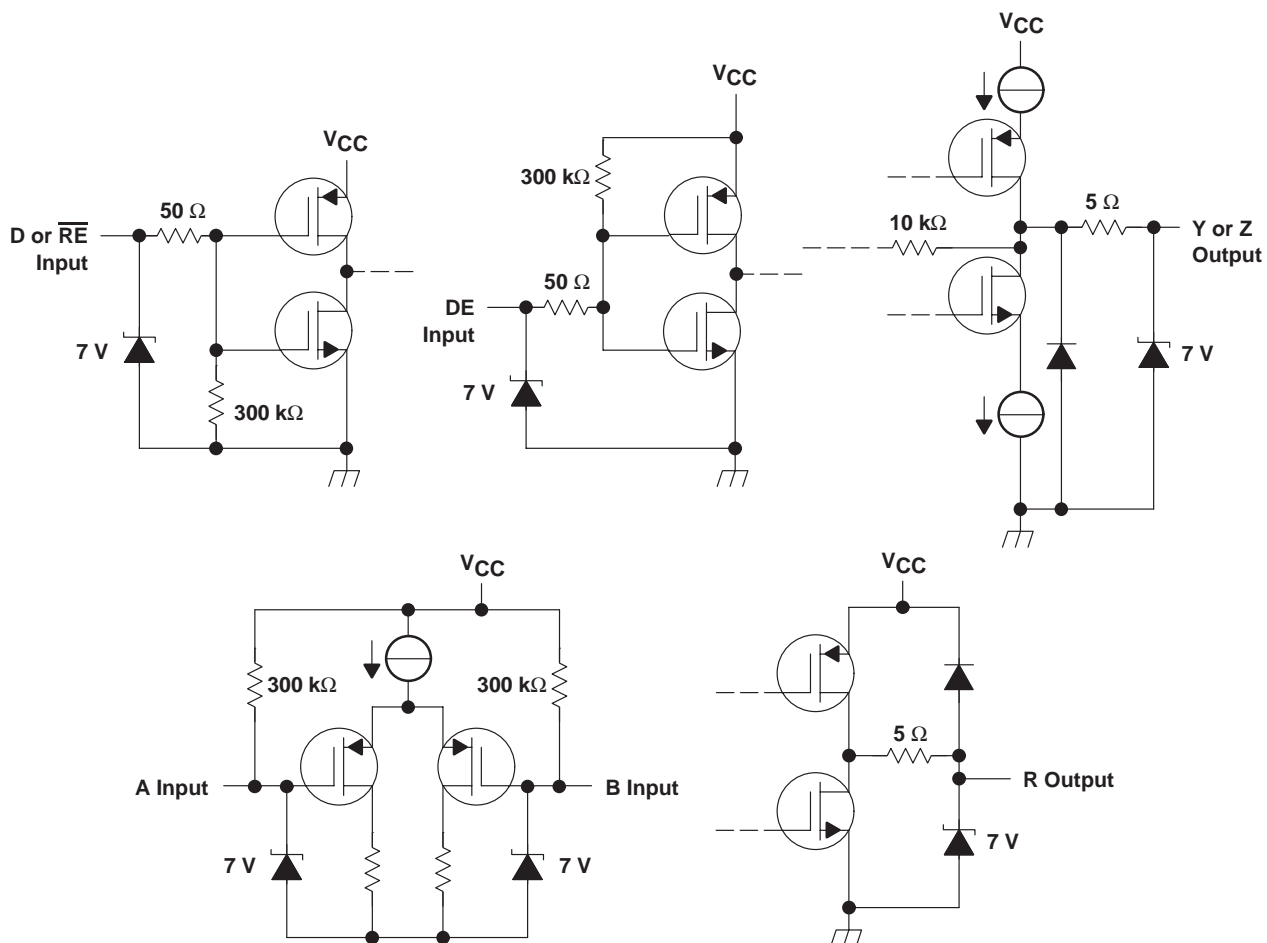
INPUTS		OUTPUTS	
D	DE	Y	Z
L	H	L	H
H	H	H	L
Open	H	L	H
X	L	Z	Z

H = high level, L = low level, Z = high impedance,
X = don't care

SN75LVDS179, SN75LVDS180, SN75LVDS050, SN75LVDS051 HIGH-SPEED DIFFERENTIAL LINE DRIVERS AND RECEIVERS

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equivalent input and output schematic diagrams



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absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage range, V_{CC} (see Note 1)	–0.5 V to 4 V
Voltage range (D, R, DE, \overline{RE})	–0.5 V to 6 V
Continuous power dissipation	see dissipation rating table
Storage temperature range	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	250°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential I/O bus voltages are with respect to network ground terminal.
2. Tested in accordance with MIL-STD-883C Method 3015.7.

DISSIPATION RATING TABLE

PACKAGE	$T_A \leq 25^\circ\text{C}$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25^\circ\text{C}$ †	$T_A = 70^\circ\text{C}$ POWER RATING
D8	725 mW	5.8 mW/°C	464 mW
D14 or D16	950 mW	7.8 mW/°C	608 mW

† This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	3	3.3	3.6	V
High-level input voltage, V_{IH}	2			V
Low-level input voltage, V_{IL}			0.8	V
Magnitude of differential input voltage, $ V_{ID} $	0.1		0.6	V
Common-mode input voltage, V_{IC} (see Figure 6)	$\frac{ V_{ID} }{2}$	2.4	$-\frac{ V_{ID} }{2}$	V
		$V_{CC}-0.8$		
Operating free-air temperature, T_A	0		70	°C



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device electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
I _{CC} Supply current	SN75LVDS179	No receiver load, driver R _L = 100 Ω		9	12	mA
	SN75LVDS180	Driver and receiver enabled, No receiver load, Driver R _L = 100 Ω		9	12	mA
		Driver enabled, receiver disabled, R _L = 100 Ω		5	7	
		Driver disabled, receiver enabled, No load		1.5	2	
		Disabled		0.5	1	
	SN75LVDS050	Drivers and receivers enabled, no receiver loads, Driver R _L = 100 Ω		12	20	mA
		Drivers enabled, receivers disabled, R _L = 100 Ω		10	16	
		Drivers disabled, receivers enabled, no loads		3	6	
		Disabled		0.5	1	
	SN75LVDS051	Drivers enabled, no receiver loads, driver R _L = 100 Ω		12	20	mA
		Drivers disabled, No loads		3	6	

† All typical values are at 25°C and with a 3.3-V supply.

driver electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V _{OD}	Differential output voltage magnitude	R _L = 100Ω, See Figure 1 and Figure 2	247	340	454	mV
Δ V _{OD}	Change in differential output voltage magnitude between logic states		–50		50	
V _{OC(SS)}	Steady-state common-mode output voltage	See Figure 3	1.125	1.2	1.375	V
ΔV _{OC(SS)}	Change in steady-state common-mode output voltage between logic states		–50		50	mV
V _{OC(PP)}	Peak-to-peak common-mode output voltage			50	150	mV
I _{IH}	High-level input current	DE	V _{IH} = 5 V	–0.5	–20	μA
		D		2	20	
I _{IL}	Low-level input current	DE	V _{IL} = 0.8 V	–0.5	–10	μA
		D		2	10	
I _{OS}	Short-circuit output current	V _{OY} or V _{OZ} = 0 V		3	10	mA
		V _{OD} = 0 V		3	10	
I _{OZ}	High-impedance output current	V _{OD} = 600 mV			±1	μA
		V _O = 0 V or V _{CC}			±1	
I _{O(OFF)}	Power-off output current	V _{CC} = 0 V, V _O = 3.6 V			±1	μA
C _{IN}	Input capacitance			3		pF



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receiver electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
V _{ITH+} Positive-going differential input voltage threshold	See Figure 5 and Table 1			100	mV
V _{ITH-} Negative-going differential input voltage threshold		-100			
V _{OH} High-level output voltage	I _{OH} = -8 mA	2.4			V
V _{OL} Low-level output voltage	I _{OL} = 8 mA			0.4	V
I _I Input current (A or B inputs)	V _I = 0	-2	-11	-20	μA
	V _I = 2.4 V	-1.2	-3		
I _{I(OFF)} Power-off input current (A or B inputs)	V _{CC} = 0			±20	μA
I _{IH} High-level input current (enables)	V _{IH} = 5 V			±10	μA
I _{IL} Low-level input current (enables)	V _{IL} = 0.8 V			±10	μA
I _{OZ} High-impedance output current	V _O = 0 or 5 V			±10	μA
C _I Input capacitance			5		pF

† All typical values are at 25°C and with a 3.3-V supply.

driver switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t _{PLH} Propagation delay time, low-to-high-level output	R _L = 100Ω, C _L = 10 pF, See Figure 6			6	ns
t _{PHL} Propagation delay time, high-to-low-level output				6	ns
t _r Differential output signal rise time		0.8	1.2		ns
t _f Differential output signal fall time		0.8	1.2		ns
t _{sk(p)} Pulse skew (t _{pHL} - t _{pLH})‡				0.6	ps
t _{sk(o)} Channel-to-channel output skew§				0.6	ps
t _{sk(pp)} Part-to-part skew¶				1	ps
t _{PZH} Propagation delay time, high-impedance-to-high-level output	See Figure 7			25	ns
t _{PZL} Propagation delay time, high-impedance-to-low-level output				25	ns
t _{PHZ} Propagation delay time, high-level-to-high-impedance output				25	ns
t _{pLZ} Propagation delay time, low-level-to-high-impedance output				25	ns

† All typical values are at 25°C and with a 3.3-V supply.

‡ t_{sk(p)} is the magnitude of the time difference between the high-to-low and low-to-high propagation delay times at an output

§ t_{sk(o)} is the magnitude of the time difference between the outputs of a single device with all of their inputs connected together.

¶ t_{sk(pp)} is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, same temperature, and have identical packages and test circuits.

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receiver switching characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t_{PLH} Propagation delay time, low-to-high-level output	$C_L = 10 \text{ pF}$, See Figure 6		2.1	6	ns
t_{PHL} Propagation delay time, high-to-low-level output			2.1	6	ns
t_r Output signal rise time			0.6	1.5	ns
t_f Output signal fall time			0.7	1.5	ns
$t_{sk(p)}$ Pulse skew ($ t_{pHL} - t_{pLH} $)‡				0.6	ns
$t_{sk(o)}$ Channel-to-channel output skew§				0.6	ns
$t_{sk(pp)}$ Part-to-part skew¶				1	ns
t_{PZH} Propagation delay time, high-level-to-high-impedance output	See Figure 7			25	ns
t_{PZL} Propagation delay time, low-level-to-low-impedance output				25	ns
t_{PHZ} Propagation delay time, high-impedance-to-high-level output				25	ns
t_{PLZ} Propagation delay time, low-impedance-to-high-level output				25	ns

† All typical values are at 25°C and with a 3.3-V supply.

‡ $t_{sk(p)}$ is the magnitude of the time difference between the high-to-low and low-to-high propagation delay times at an output

§ $t_{sk(o)}$ is the magnitude of the time difference between the outputs of a single device with all of their inputs connected together.

¶ $t_{sk(pp)}$ is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, same temperature, and have identical packages and test circuits.

PARAMETER MEASUREMENT INFORMATION

driver

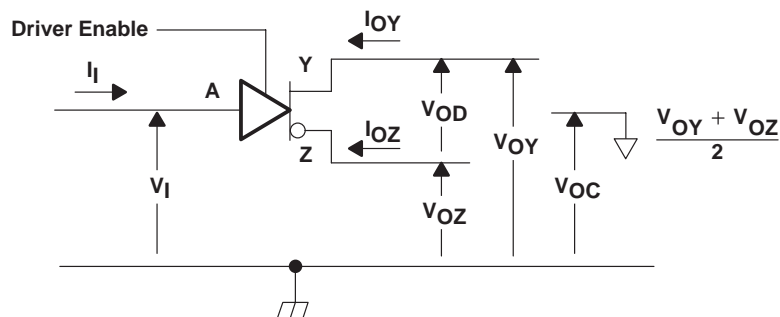
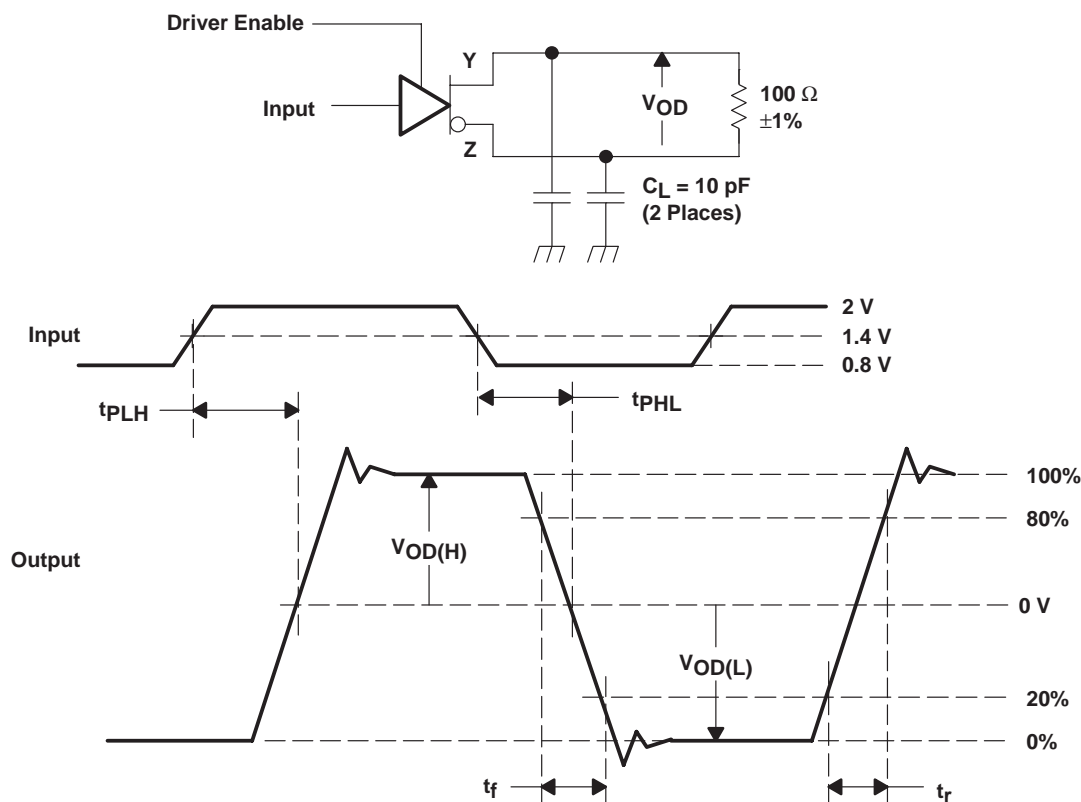


Figure 1. Driver Voltage and Current Definitions

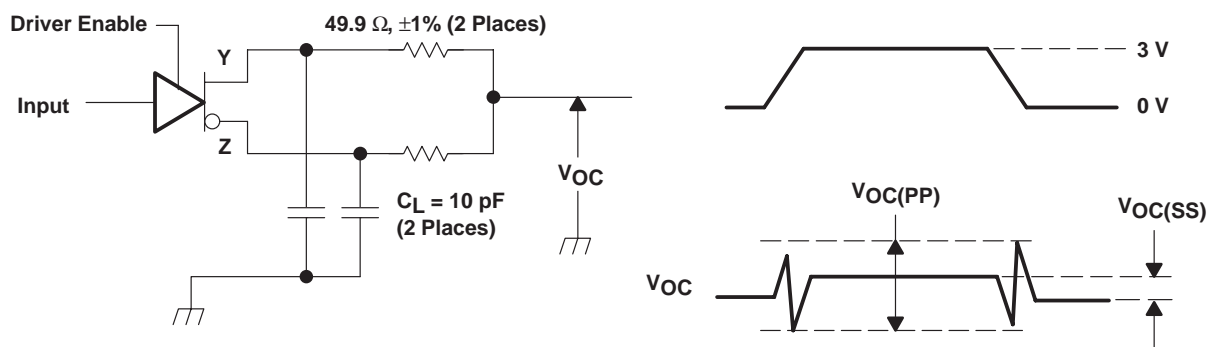
PARAMETER MEASUREMENT INFORMATION

driver (continued)



NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 ± 0.2 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T.

Figure 2. Test Circuit, Timing, and Voltage Definitions for the Differential Output Signal

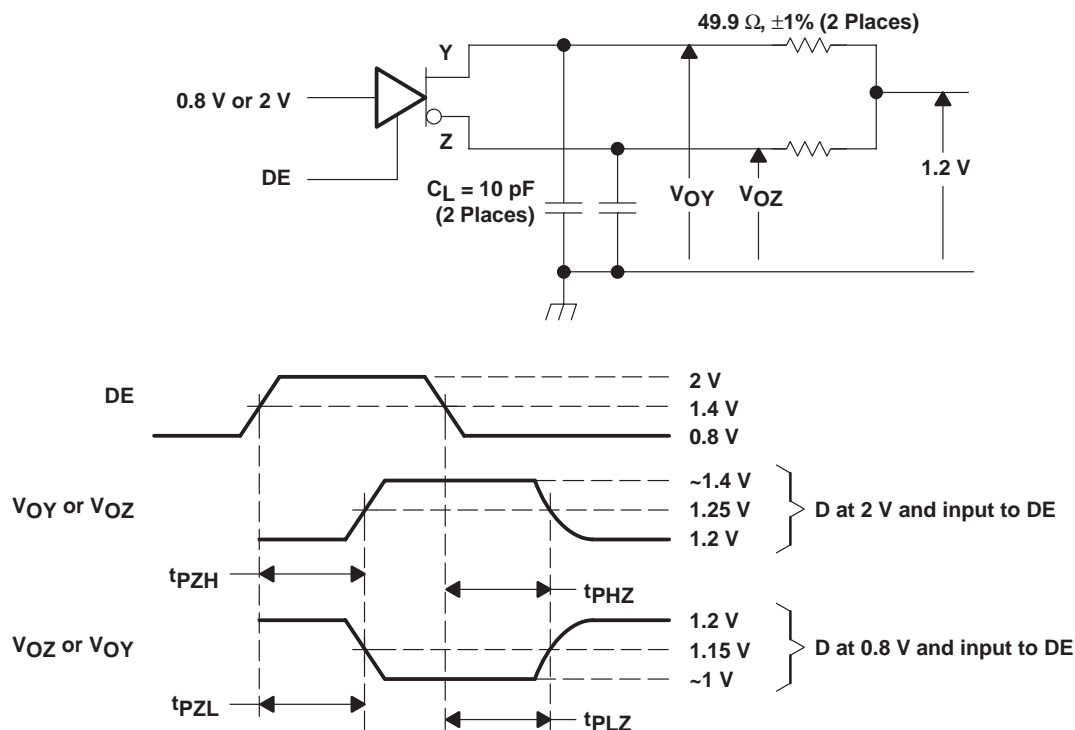


NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 50 Mpps, pulse width = 10 ± 0.2 ns. C_L includes instrumentation and fixture capacitance within 0,06 mm of the D.U.T. The measurement of $V_{OC(PP)}$ is made on test equipment with a -3 dB bandwidth of at least 300 MHz.

Figure 3. Test Circuit and Definitions for the Driver Common-Mode Output Voltage

PARAMETER MEASUREMENT INFORMATION

driver (continued)



NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1 \text{ ns}$, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = $500 \pm 10 \text{ ns}$. C_L includes instrumentation and fixture capacitance within 0.06 mm of the D.U.T.

Figure 4. Enable and Disable Time Circuit and Definitions

PARAMETER MEASUREMENT INFORMATION

receiver

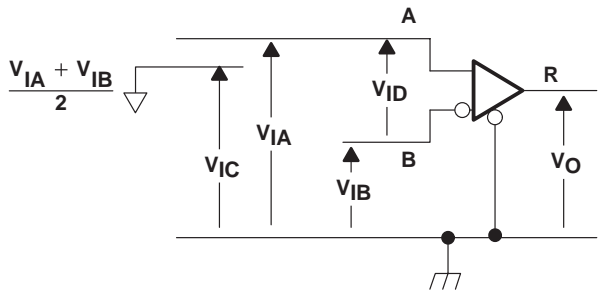


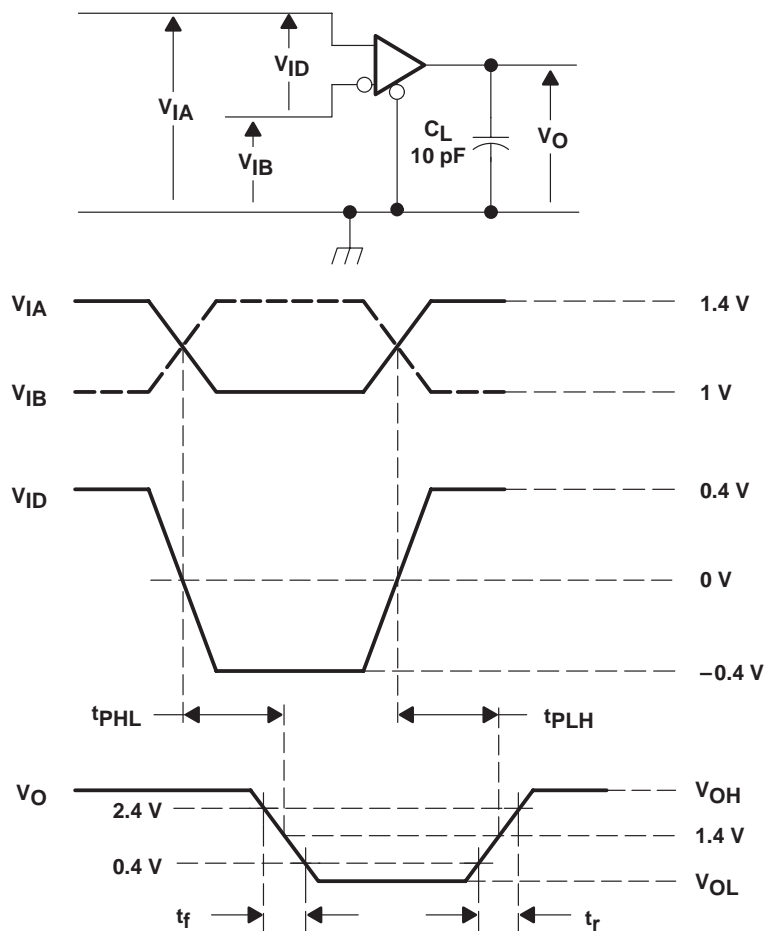
Figure 5. Receiver Voltage Definitions

Table 1. Receiver Minimum and Maximum Input Threshold Test Voltages

APPLIED VOLTAGES (V)		RESULTING DIFFERENTIAL INPUT VOLTAGE (mV)	RESULTING COMMON- MODE INPUT VOLTAGE (V)
V_{IA}	V_{IB}	V_{ID}	V_{IC}
1.25	1.15	100	1.2
1.15	1.25	-100	1.2
2.4	2.3	100	2.35
2.3	2.4	-100	2.35
0.1	0	100	0.05
0	0.1	-100	0.05
1.5	0.9	600	1.2
0.9	1.5	-600	1.2
2.4	1.8	600	2.1
1.8	2.4	-600	2.1
0.6	0	600	0.3
0	0.6	-600	0.3

PARAMETER MEASUREMENT INFORMATION

receiver (continued)



NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1 \text{ ns}$, pulse repetition rate (PRR) = 50 Mpps, pulse width = $10 \pm 0.2 \text{ ns}$. C_L includes instrumentation and fixture capacitance within 0.06 m of the D.U.T.

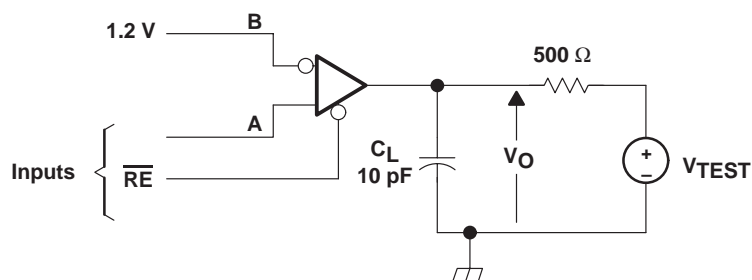
Figure 6. Timing Test Circuit and Waveforms

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PARAMETER MEASUREMENT INFORMATION

receiver (continued)



NOTE A: All input pulses are supplied by a generator having the following characteristics: t_r or $t_f \leq 1$ ns, pulse repetition rate (PRR) = 0.5 Mpps, pulse width = 500 ± 10 ns. C_L includes instrumentation and fixture capacitance within 0,06 m of the D.U.T.

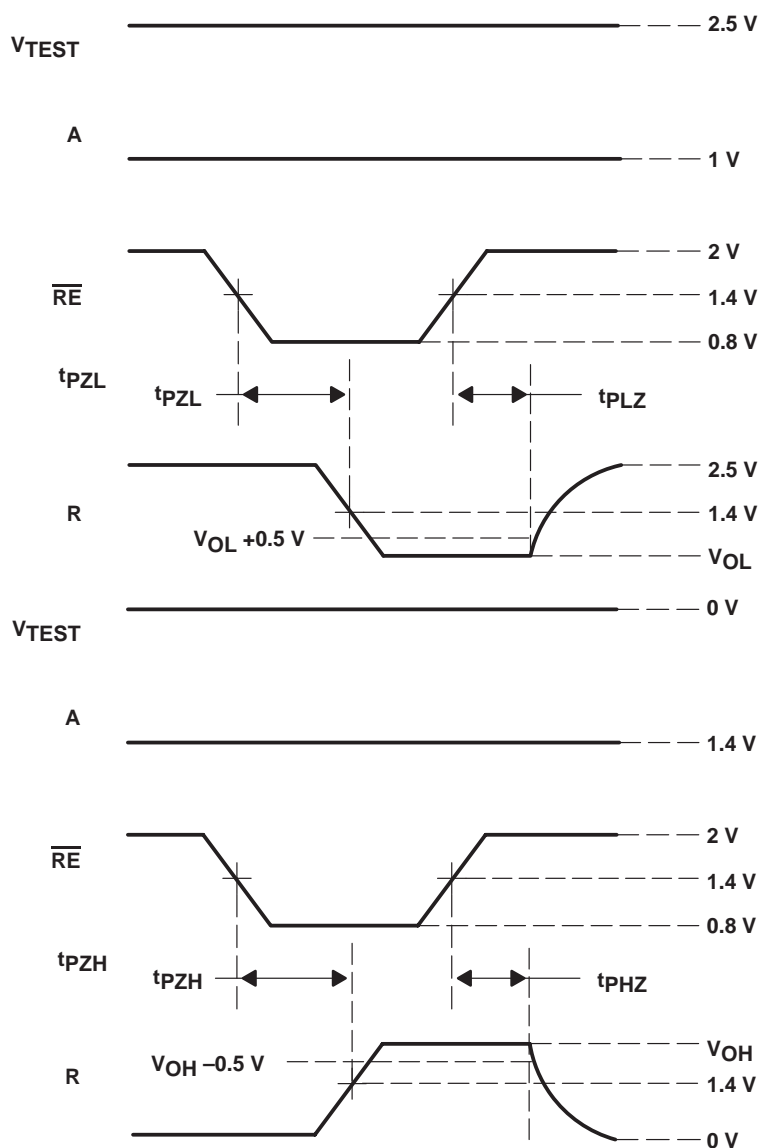


Figure 7. Enable/Disable Time Test Circuit and Waveforms

TYPICAL CHARACTERISTICS

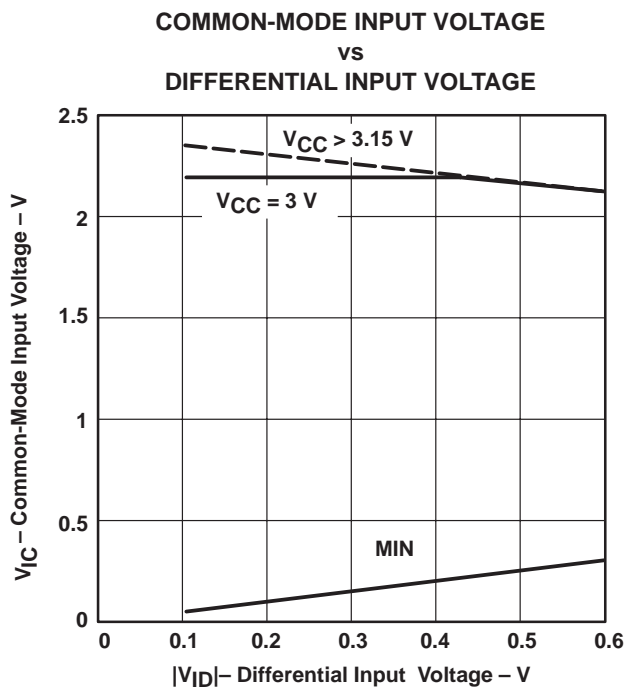


Figure 8

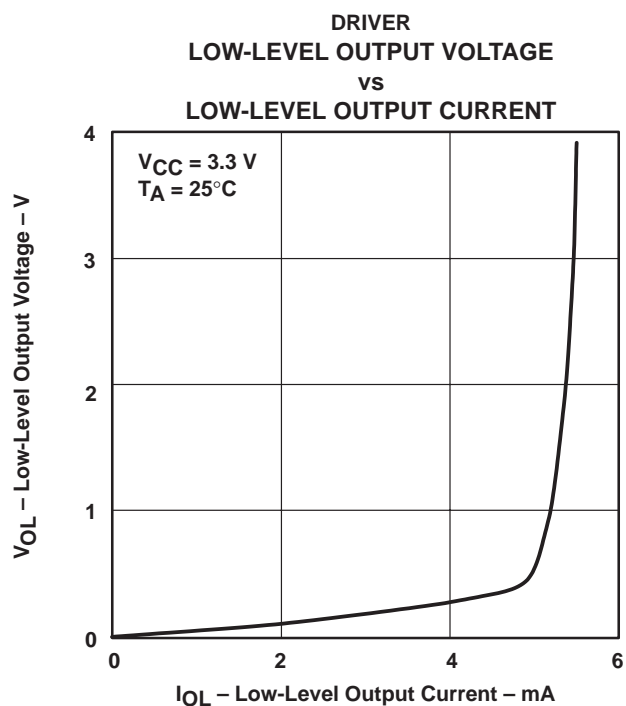


Figure 9

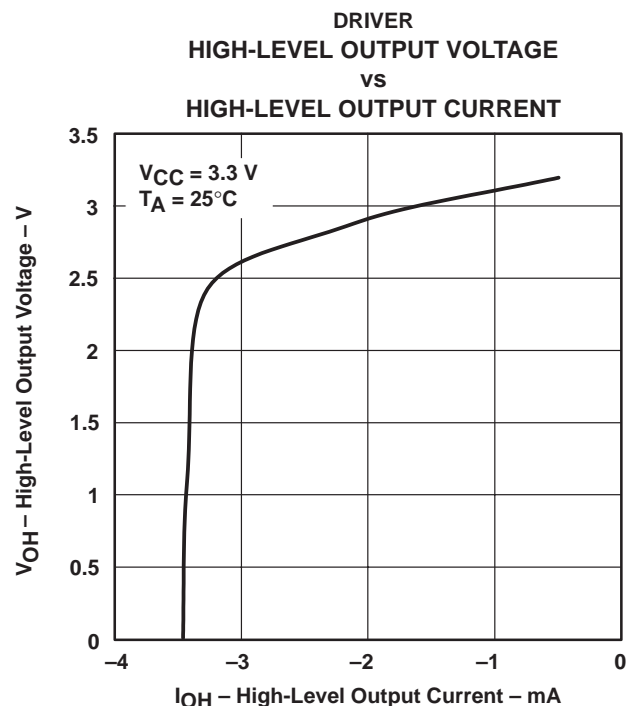


Figure 10

SN75LVDS179, SN75LVDS180, SN75LVDS050, SN75LVDS051
HIGH-SPEED DIFFERENTIAL LINE DRIVERS AND RECEIVERS

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TYPICAL CHARACTERISTICS

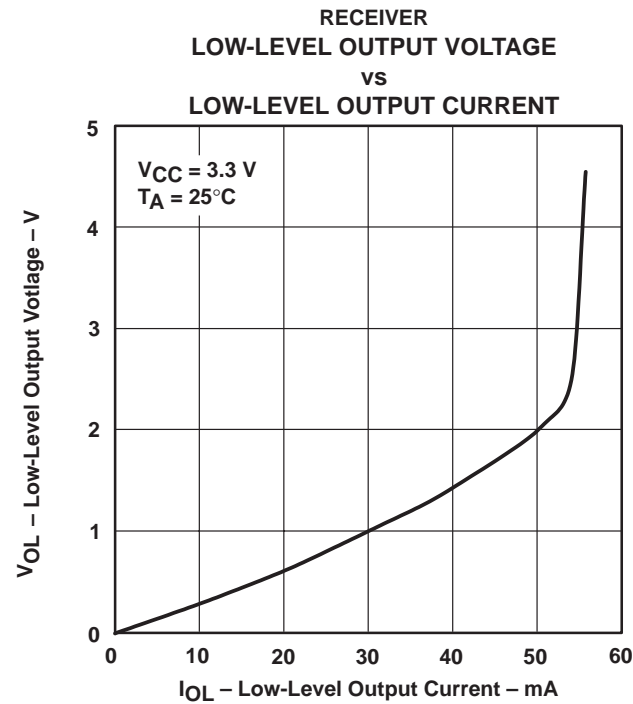


Figure 11

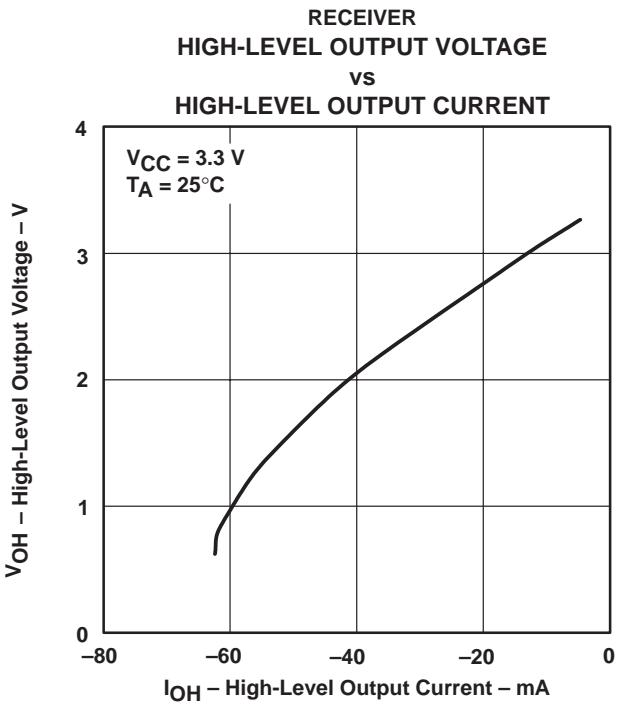


Figure 12

APPLICATION INFORMATION

The devices are generally used as building blocks for high-speed point-to-point data transmission. Ground differences are less than 1 V with a low common-mode output and balanced interface for very low noise emissions. Devices can interoperate with RS-422, PECL, and IEEE-P1596. Drivers/Receivers maintain ECL speeds without the power and dual supply requirements.

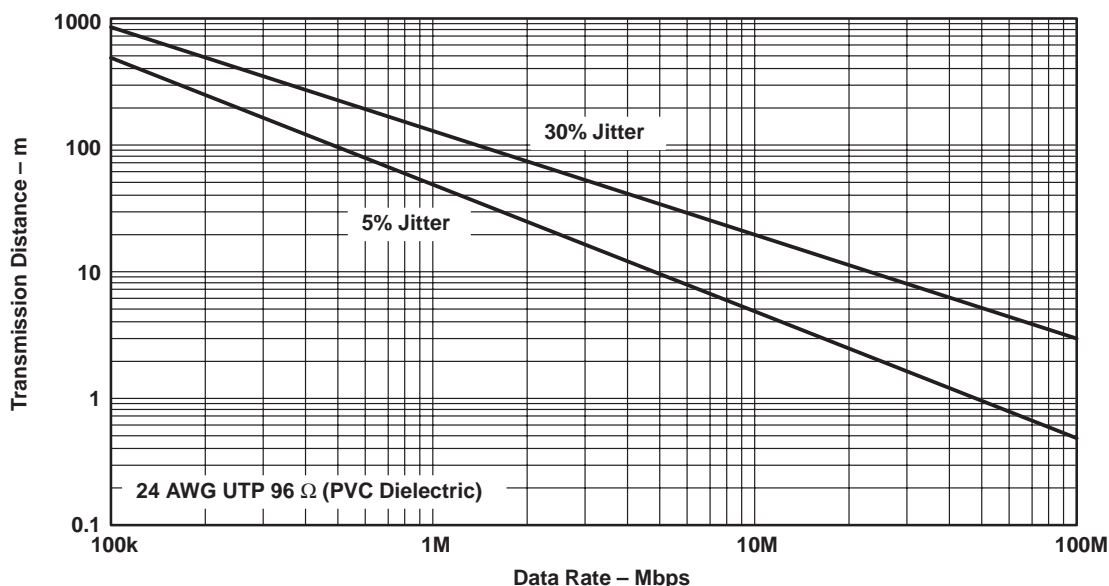


Figure 13. Data Transmission Distance Versus Rate

APPLICATION INFORMATION

fail safe

One of the most common problems with differential signaling applications is how the system responds when no differential voltage is present on the signal pair. The LVDS receiver is like most differential line receivers, in that its output logic state can be indeterminate when the differential input voltage is between -100 mV and 100 mV and within its recommended input common-mode voltage range. TI's LVDS receiver is different in how it handles the open-input circuit situation, however.

Open-circuit means that there is little or no input current to the receiver from the data line itself. This could be when the driver is in a high-impedance state or the cable is disconnected. When this occurs, the LVDS receiver will pull each line of the signal pair to near V_{CC} through $300\text{-k}\Omega$ resistors as shown in Figure 14. The fail-safe feature uses an AND gate with input voltage thresholds at about 2.3 V to detect this condition and force the output to a high-level regardless of the differential input voltage.

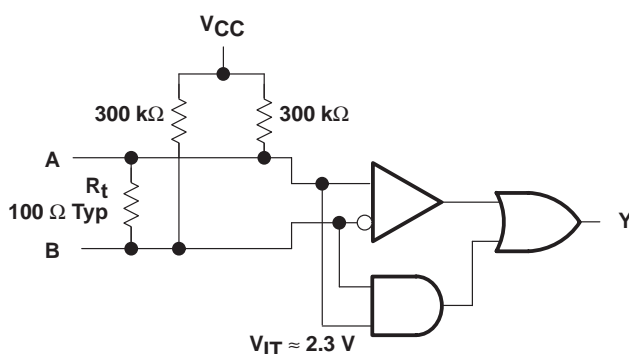


Figure 14. Open-Circuit Fail Safe of the LVDS Receiver

It is only under these conditions that the output of the receiver will be valid with less than a 100-mV differential input voltage magnitude. The presence of the termination resistor, R_t , does not affect the fail-safe function as long as it is connected as shown in the figure. Other termination circuits may allow a dc current to ground that could defeat the pullup currents from the receiver and the fail-safe feature.

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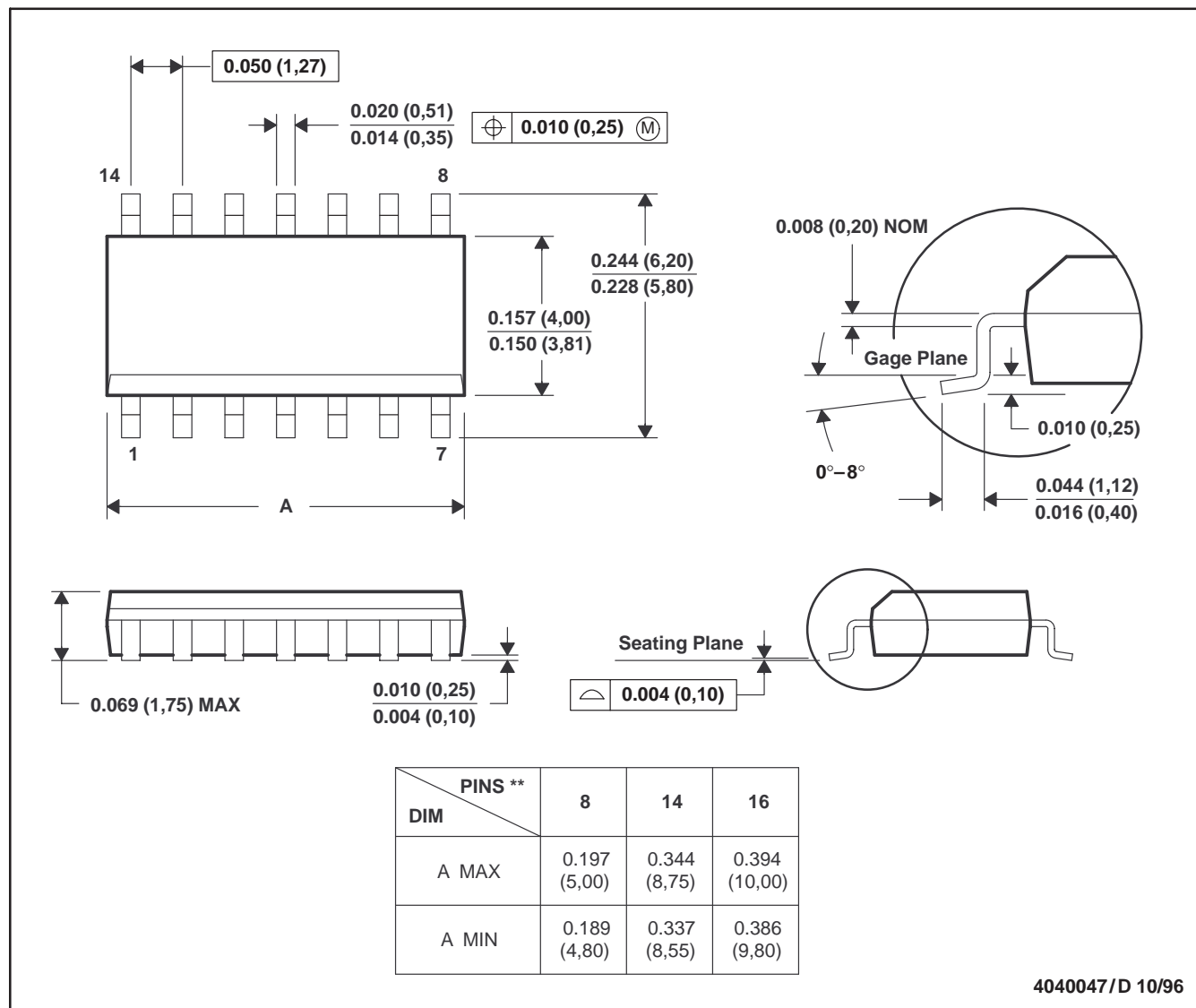
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MECHANICAL DATA

D (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14 PIN SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0.006 (0,15).
 D. Falls within JEDEC MS-012

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN75LVDS051D	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	75LVDS051
SN75LVDS051D.B	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	75LVDS051

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

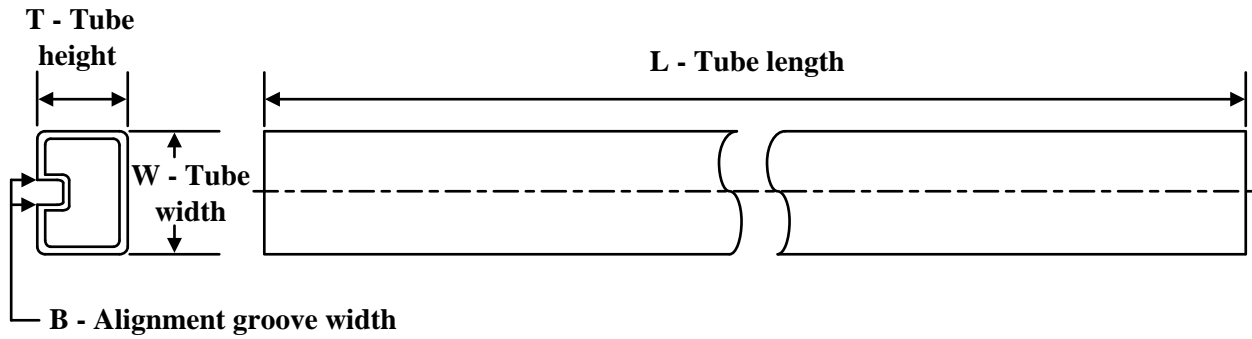
⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN75LVDS051D	D	SOIC	16	40	505.46	6.76	3810	4
SN75LVDS051D.B	D	SOIC	16	40	505.46	6.76	3810	4

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